



Product Status Information

HL8341MG-A is Not Recommended for New Design (NRND) status. Please refer to successor product below for new design and adoption.

NRND Product	Successor Product
HL8341MG-A	HL85021MG
https://www.ushio.co.jp/jp/products/product_file/file/UIE_DS_HL8341MG.pdf	https://www.ushio.co.jp/jp/products/product_file/file/UIE_DS_HL85021MG.pdf

For the “Product Life Cycle” definition, please refer to below link.

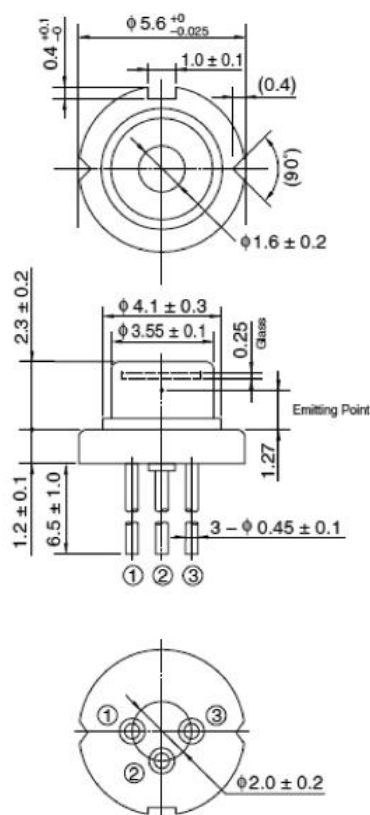
Japanese; <https://www.ushio.co.jp/jp/laser/news/500958.html>

English; <https://www.ushio.co.jp/en/laser/news/500958.html>

HL8340MG-A/41MG-A

852nm / 50mW GaAlAs Laser Diode

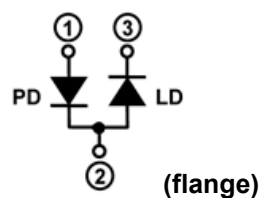
Outline



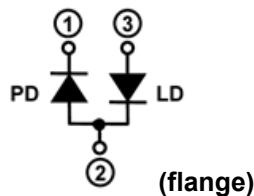
(Unit:mm)

Internal Circuit

HL8340MG-A



HL8341MG-A



Features

- Operation temperature: -10~+60°C
- Optical output power: 50mW(CW)
- Infrared lasing: 852nm Typ.
- Low operating voltage: 2.4V Max.
- Package: $\phi 5.6$ mm
- Single transverse mode
- TE mode oscillation

Application

- Sensor application
- Night vision
- Machine vision
- Light source of optical equipments

HL8340MG-A/41MG-A

Data Sheet

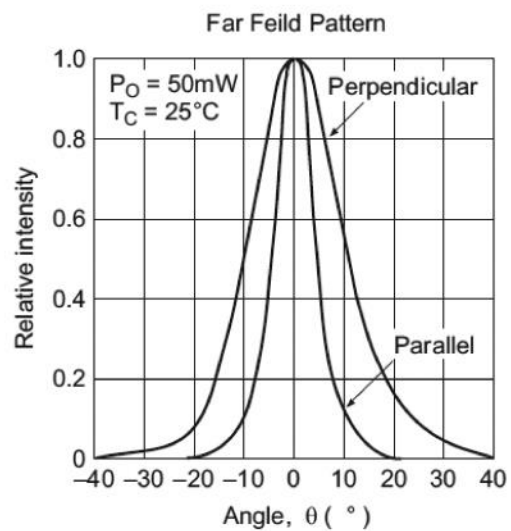
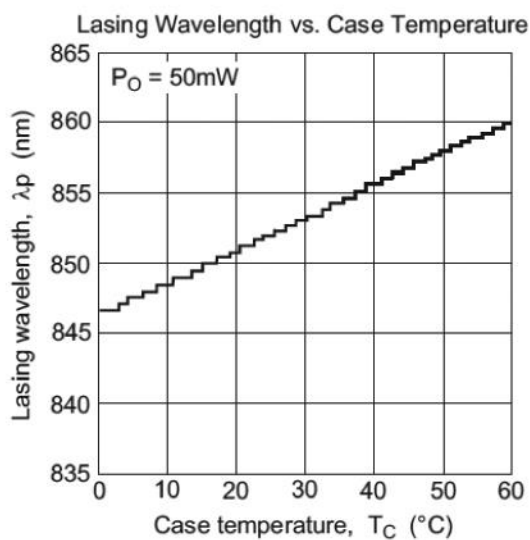
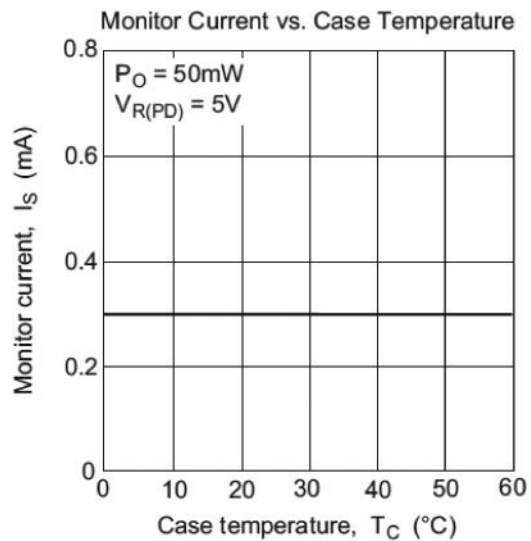
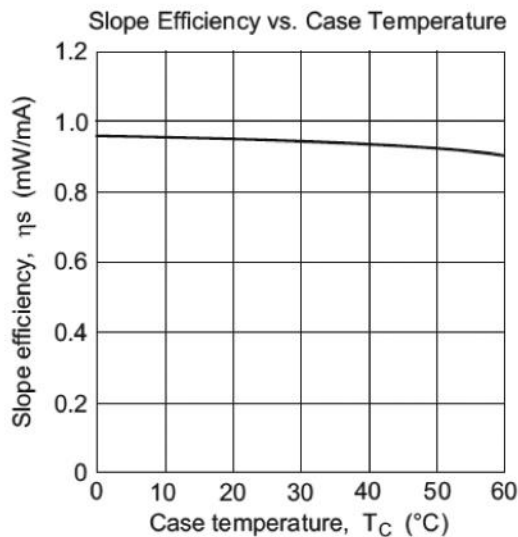
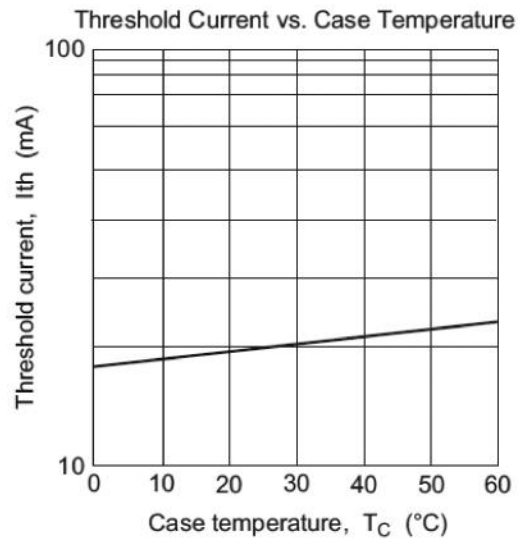
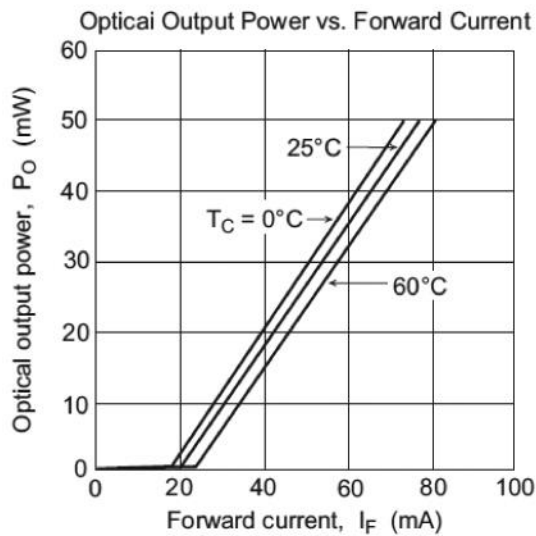
Absolute Maximum Ratings (Tc=25°C)

Item	Symbol	Ratings	Unit
Optical output power	Po	50	mW
LD Reverse Voltage	V _{R(LD)}	2	V
PD Reverse Voltage	V _{R(PD)}	30	V
Operating Temperature	Topr	-10 ~ +60	°C
Storage Temperature	Tstg	-40 ~ +85	°C

Optical and Electrical Characteristics (Tc=25°C)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Threshold current	I _{th}	-	20	40	mA	-
Operating current	I _{op}	-	75	100	mA	Po=50mW
Operating voltage	V _{op}	-	1.9	2.4	V	Po=50mW
Beam divergence Parallel to the junction	θ//	6	9	12	°	Po=50mW, FWHM
Beam divergence Perpendicular to the junction	θ⊥	18	22	26	°	Po=50mW, FWHM
Lasing Wavelength	λ _p	842	852	862	nm	Po=50mW
Monitor Current	I _s	0.10	0.25	0.50	mA	Po=50mW, V _{R(PD)} =5V

Typical Characteristic Curves



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